

DESCRIPTION

The MXB6888 is N-channel MOS Field Effect Transistor designed for high current switching applications. Rugged E_{AS} capability and ultra low $R_{DS(ON)}$ is suitable for PWM, load switching especially for E-Bike controller applications.

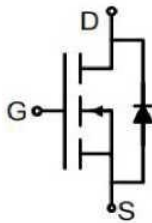
GENERAL FEATURES

- $V_{DS}=68V$, $I_D=80A$ @ $V_{GS}=10V$
 $R_{DS(ON)}$ (Typ.)= $6.8m\Omega$ @ $V_{GS}=10V$
- Special Designed for E-Bike Controller Application
- Ultra Low On-Resistance
- High UIS and UIS 100% Test

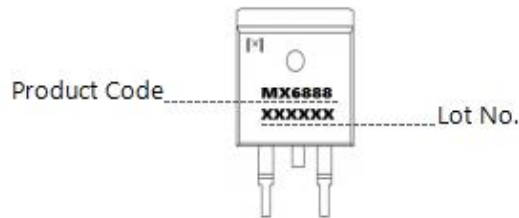
APPLICATION

- 48V E-Bike Controller Applications
- Hard Switched and High Frequency Circuits
- Uninterruptible Power Supply

PINOUT



Schematic diagram



Marking and pin Assignment



TO-263 top view

PACKAGE INFORMATION

| Package | Storage Temperature | Package | Devices Per Reel |
|---------|---------------------|---------|------------------|
| MXB6888 | -55°C to 175°C | TO-263 | - |

ABSOLUTE MAXIMUM RATINGS ($T_A=25^\circ C$ unless otherwise noted)

| Parameter | Symbol | Limit | Unit |
|--|-----------------|------------|---------------|
| Drain-Source Voltage ($V_{GS}=0V$) | V_{DS} | 68 | V |
| Gate-Source Voltage ($V_{DS}=0V$) | V_{GS} | ± 20 | V |
| Drain Current (DC) at $T_C=25^\circ C$ | $I_{D(DC)}$ | 80 | A |
| Drain Current (DC) at $T_C=100^\circ C$ | $I_{D(DC)}$ | 45 | A |
| Drain Current-Continuous@ Current-Pulsed (Note1) | $I_{DM(pluse)}$ | 260 | A |
| Peak Diode Recovery Voltage | dv/dt | 8 | V/ns |
| Maximum Power Dissipation($T_C=25^\circ C$) | P_D | 75 | W |
| Derating Factor | | 0.5 | W/ $^\circ C$ |
| Single Pulse Avalanche Energy (Note 2) | E_{AS} | 300 | mJ |
| Operating Junction and Storage Temperature Range | T_J, T_{STG} | -55 to 175 | $^\circ C$ |

THERMAL RESISTANCE

| Parameter | Symbol | Max. | Unit |
|--------------------------------------|-----------------|------|--------------|
| Thermal Resistance, Junction-to-Case | $R_{\theta JC}$ | 2.34 | $^\circ C/W$ |

Note 1. Repetitive Rating: Pulse width limited by maximum junction temperature

Note 2. E_{AS} condition: $T_J=25^\circ C$, $V_{DD}=33V$, $V_G=10V$


ELECTRICAL CHARACTERISTICS ($T_A=25^\circ\text{C}$ unless otherwise noted)

| Parameter | Symbol | Condition | Min | Typ | Max | Unit |
|-----------|--------|-----------|-----|-----|-----|------|
|-----------|--------|-----------|-----|-----|-----|------|

On/Off Characteristics

| | | | | | | |
|----------------------------------|--------------|-------------------------------|----|-----|-----------|------------|
| Drain-Source Breakdown Voltage | BV_{DSS} | $V_{GS}=0V, I_D=250\mu A$ | 68 | - | - | V |
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{DS}=64V, V_{GS}=0V$ | - | - | 1 | μA |
| Gate-Body Leakage Current | I_{GSS} | $V_{GS}=\pm 20V, V_{DS}=0V$ | - | - | ± 100 | nA |
| Gate Threshold Voltage | $V_{GS(th)}$ | $V_{DS}=V_{GS}, I_D=250\mu A$ | 2 | - | 4 | V |
| Drain-Source On-State Resistance | $R_{DS(ON)}$ | $V_{GS}=10V, I_D=40A$ | - | 6.8 | 8.2 | m Ω |

Dynamic Characteristics

| | | | | | | |
|------------------------------|-----------|-----------------------------------|----|------|---|----|
| Forward Transconductance | g_{FS} | $V_{DS}=10V, I_D=15A$ | 15 | - | - | S |
| Input Capacitance | C_{iss} | $V_{DS}=25V, V_{GS}=0V, F=1.0MHz$ | - | 2873 | - | pF |
| Output Capacitance | C_{oss} | | - | 252 | - | pF |
| Reverse Transfer Capacitance | C_{rss} | | - | 205 | - | pF |
| Total Gate Charge | Q_g | $V_{DS}=50V, I_D=40A, V_{GS}=10V$ | - | 56 | - | nC |
| Gate-Source Charge | Q_{gs} | | - | 10 | - | nC |
| Gate-Drain Charge | Q_{gd} | | - | 16 | - | nC |

Switching Characteristics

| | | | | | | |
|---------------------|--------------|---|---|------|---|----|
| Turn-on Delay Time | $t_{d(on)}$ | $V_{DD}=30V, I_D=2A, R_L=15\Omega, V_{GS}=10V, R_{GEN}=2.5\Omega$ | - | 14.5 | - | nS |
| Turn-on Rise Time | t_r | | - | 24 | - | nS |
| Turn-Off Delay Time | $t_{d(off)}$ | | - | 45 | - | nS |
| Turn-Off Fall Time | t_f | | - | 22 | - | nS |

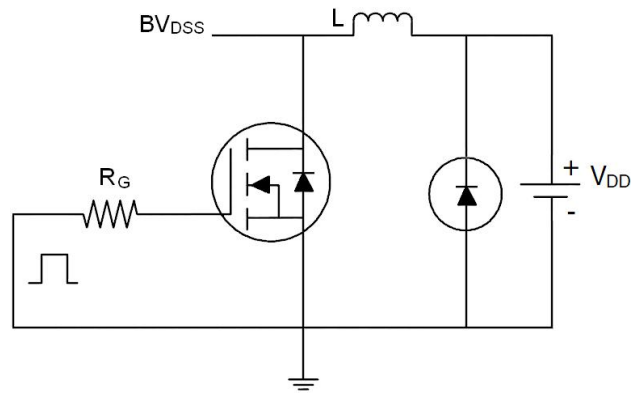
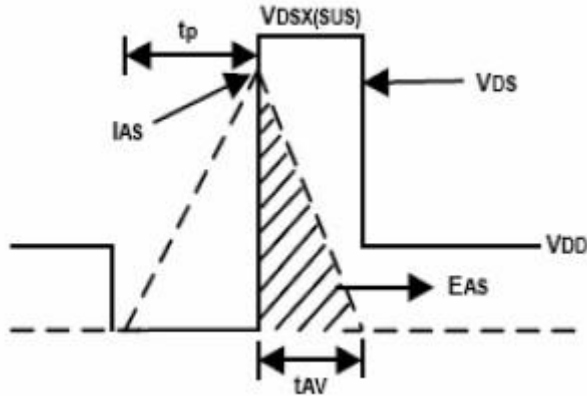
Source-Drain Diode Characteristics

| | | | | | | |
|--|----------|---|---|------|------|----|
| Forward On Voltage ^(Note1) | V_{SD} | $T_J=25^\circ\text{C}, V_{GS}=0V, I_S=40A$ | - | 0.89 | 0.99 | V |
| Source-Drain Current(Body Diode) | I_{SD} | | - | 65 | - | A |
| Pulsed Source-Drain Current(Body Diode) | | | - | 260 | - | A |
| Reverse Recovery Time ^(Note1) | t_{rr} | $T_J=25^\circ\text{C}, I_F=75A, di/dt=100A/\mu s$ | - | 22 | - | nS |
| Reverse Recovery Charge ^(Note1) | Q_{rr} | | - | 27 | - | nC |
| Forward Turn-On Time | t_{on} | Intrinsic turn-on time is negligible (turn-on is dominated by L_S+L_D) | | | | |

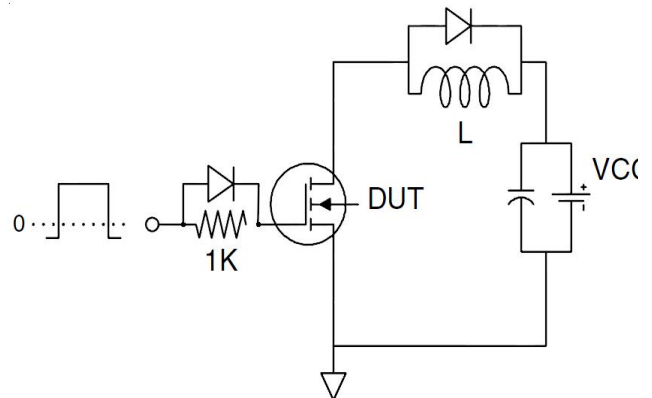
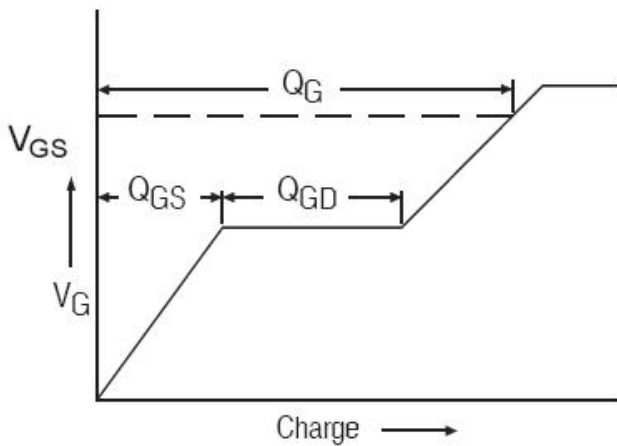
Notes 1. Pulse Test: Pulse Width $\leq 300\mu s$, Duty Cycle $\leq 1.5\%$, $R_G = 25\Omega$, Starting $T_J = 25^\circ\text{C}$

TYPICAL PERFORMANCE CHARACTERISTICS

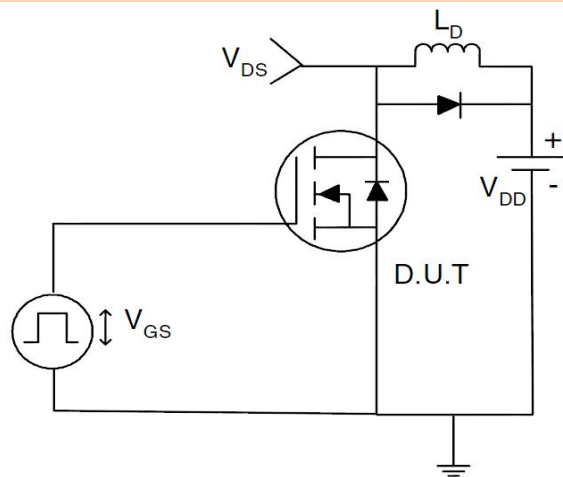
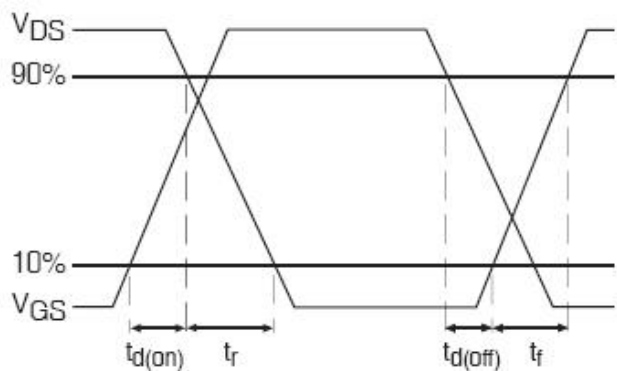
1) E_{AS} Test Circuits



2) Gate Charge Test Circuit:



3) Switch Time Test Circuit:



TYPICAL PERFORMANCE CHARACTERISTICS

Figure1. Output Characteristics

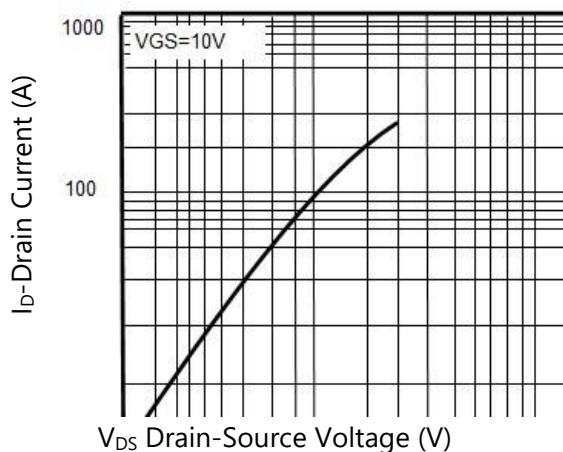


Figure2. Transfer Characteristics

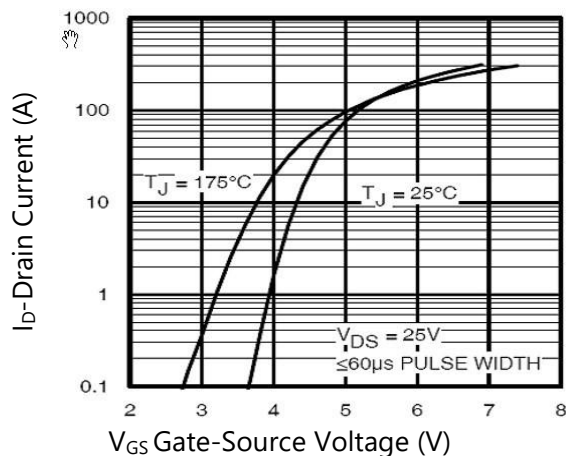


Figure3. BV_{DSS} vs Junction Temperature

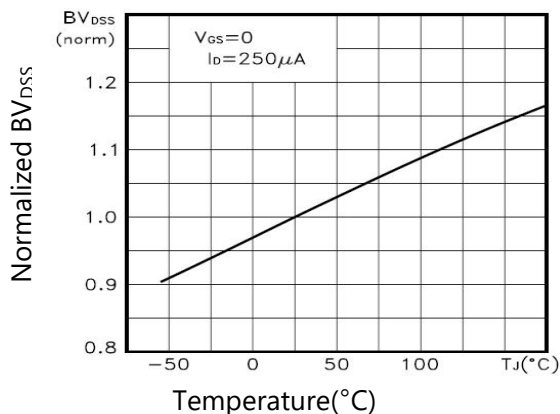


Figure4. I_D vs Junction Temperature

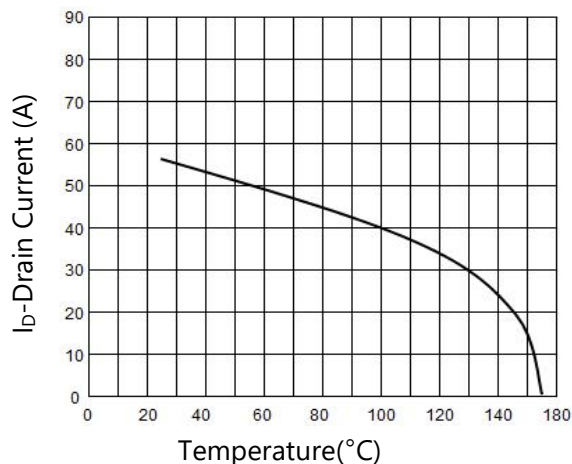


Figure5. $V_{GS(th)}$ vs Junction Temperature

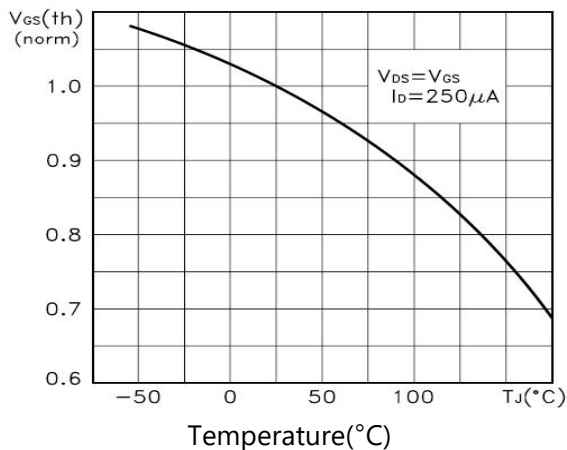
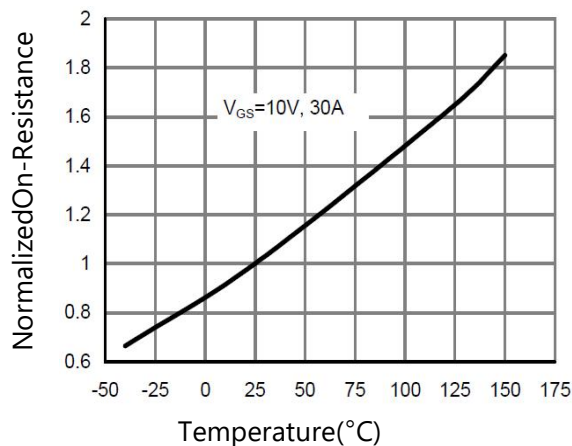


Figure6. R_{dson} Vs Junction Temperature



TYPICAL PERFORMANCE CHARACTERISTICS

Figure7. Gate Charge

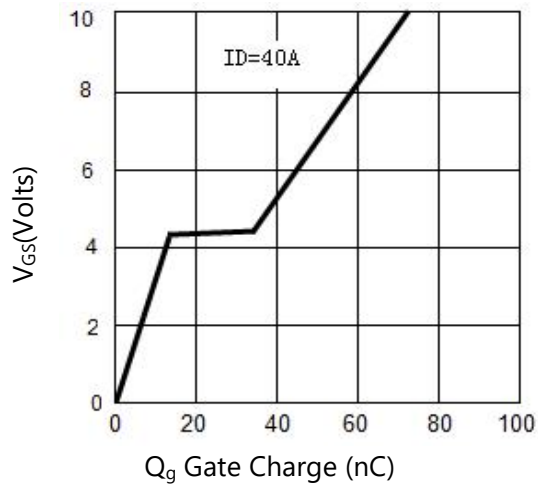


Figure8. Capacitance vs V_{DS}

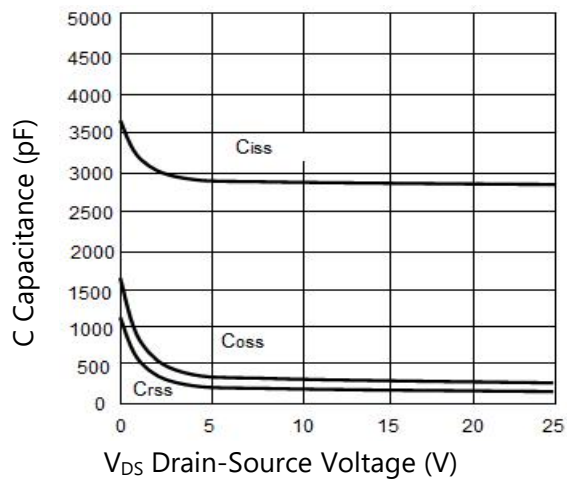


Figure9. Source- Drain Diode Forward

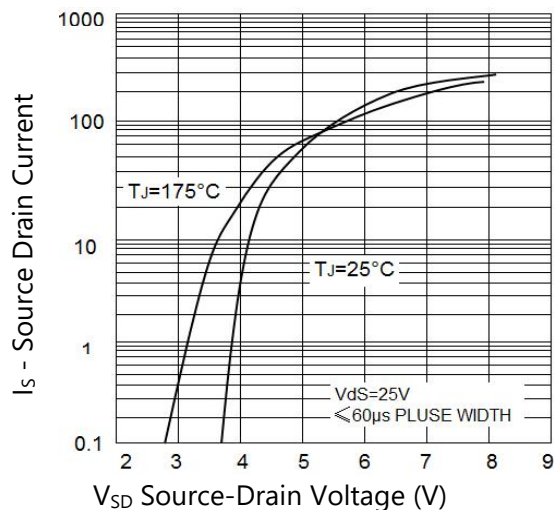


Figure10. Safe Operation Area

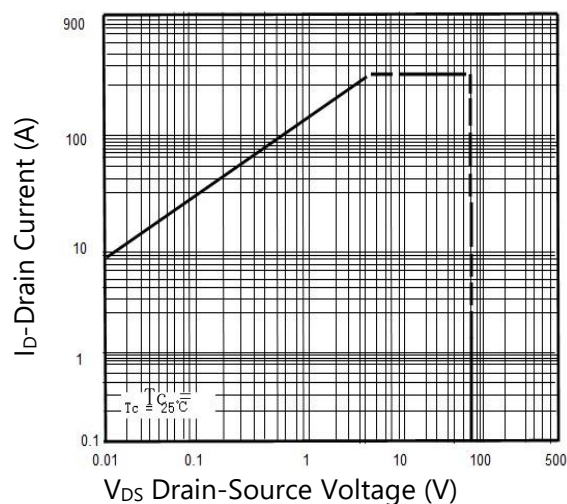
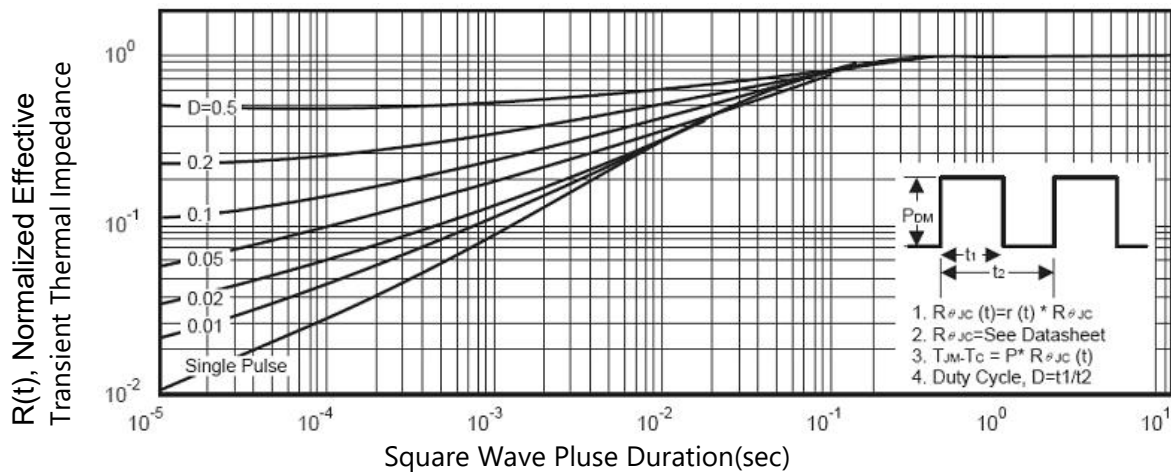
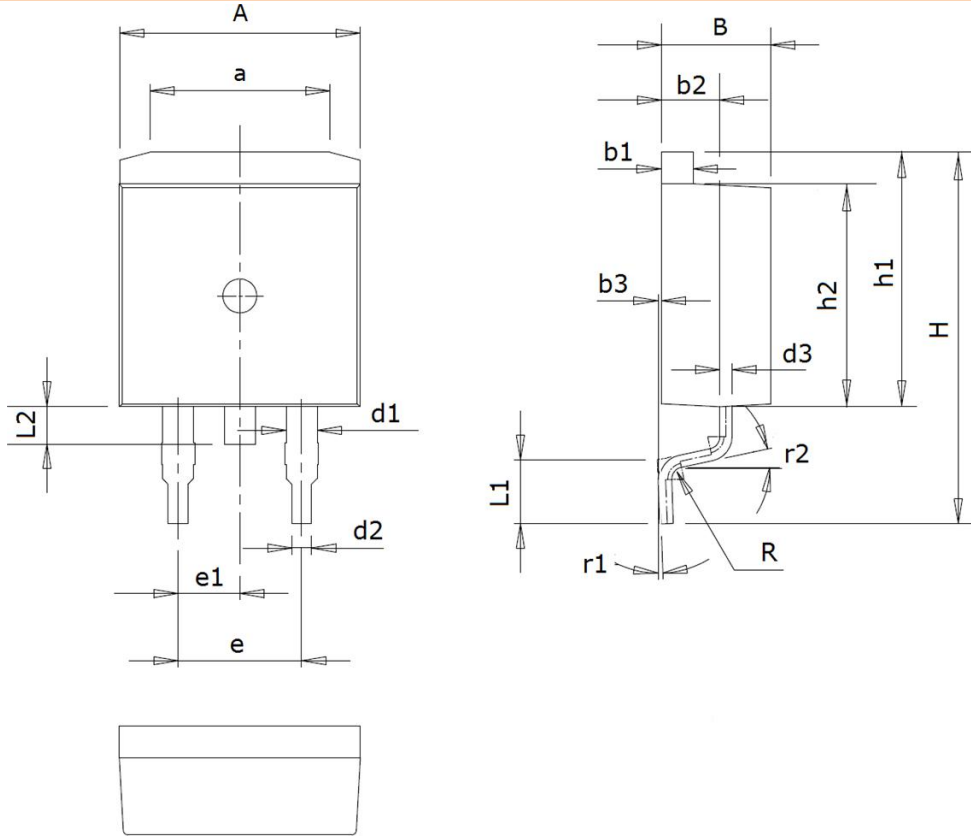


Figure11. Normalized Maximum Transient Thermal Impedance



PACKAGE INFORMATION

TO-263



| Symbol | Dimensions In Millimeters | | Dimensions In Inches | |
|--------|---------------------------|-------|----------------------|-------|
| | Min. | Max. | Min. | Max. |
| A | 9.60 | 10.0 | 0.378 | 0.394 |
| a | 7.00 | 7.80 | 0.276 | 0.307 |
| B | 4.30 | 4.70 | 0.169 | 0.185 |
| b1 | 1.25 | 1.35 | 0.049 | 0.053 |
| b2 | 2.20 | 2.60 | 0.087 | 0.102 |
| b3 | 0.00 | 0.20 | 0.000 | 0.008 |
| d1 | 1.20 | 1.40 | 0.047 | 0.055 |
| d2 | 0.70 | 0.90 | 0.028 | 0.035 |
| d3 | 0.40 | 0.60 | 0.016 | 0.024 |
| e | 5.08(typ.) | | 0.200(typ.) | |
| e1 | 2.54(typ.) | | 0.100(typ.) | |
| H | 15.20 | 15.80 | 0.598 | 0.622 |
| h1 | 10.30 | 10.70 | 0.406 | 0.421 |
| h2 | 9.10 | 9.40 | 0.358 | 0.370 |
| L1 | 2.40 | 2.90 | 0.094 | 0.114 |
| L2 | 1.30 | 1.80 | 0.051 | 0.071 |
| R | 0.5(typ.) | | 0.020(typ.) | |
| r1 | 0° | 8° | 0° | 8° |
| r2 | 12°(typ.) | | 12°(typ.) | |